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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-30CDU06-M3/I</u>

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Datasheet of VS-30CDU06-M3/I - DIODE GP 600V 2X15A TO-263AC

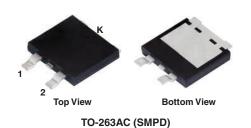
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### VS-30CDU06-M3

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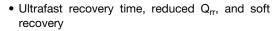
# Ultrafast Rectifier, 2 x 15 A FRED Pt®





PRODUCT SUMMARY				
Package	TO-263AC (SMPD)			
I <sub>F(AV)</sub>	2 x 15 A			
$V_{R}$	600 V			
V <sub>F</sub> at I <sub>F</sub>	0.9 V			
t <sub>rr</sub>	55 ns			
T <sub>J</sub> max.	175 °C			
Diode variation	Dual die			

### **FEATURES**





• 175 °C maximum operating junction temperature

• For PFC CRM, snubber operation

HALOGEN

FREE

Low leakage current

Low forward voltage drop

• Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

Meets JESD 201 class 2 whisker test

• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		$V_{RRM}$		600	V
A	per device	I <sub>F(AV)</sub>	T 142 °C	30	
Average rectified forward current	per diode		T <sub>solder pad</sub> = 143 °C	15	۸
Non-reportitive mode course courses	per device	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, 6 ms square pulse	300	А
Non-repetitive peak surge current	per diode			160	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	ı	-	
Forward voltage, per diode V <sub>F</sub>	W	I <sub>F</sub> = 15 A	-	1.03	1.25	V
	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	=	0.9	1.1		
Developed to the second	V <sub>R</sub> = V <sub>R</sub> rated	=	-	15		
Reverse leakage current, per diode I <sub>R</sub>		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	=	70	300	μΑ
Junction capacitance, per diode	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	13	-	pF

Revision: 10-Feb-15 Document Number: 95822



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### VS-30CDU06-M3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 50 A	Vμs, V <sub>R</sub> = 30 V	-	55	-	
Reverse recovery time t <sub>r</sub>		I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		-	-	65	
	L <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	96	-	ns
		T <sub>J</sub> = 125 °C		-	150	-	
Dools was assembled to the same of the sam		T <sub>J</sub> = 25 °C	$I_F = 15 \text{ A},$	-	18	-	^
Peak recovery current I <sub>RRM</sub>	IRRM	$T_{J} = 125 ^{\circ}\text{C}$ $dI_{F}/dt = 500 \text{A/}\mu\text{s},$ $V_{R} = 400 \text{V}$	-	26	-	A	
D	T <sub>J</sub> = 25 °C		-	1.0	-		
Reverse recovery charge	$Q_{rr}$	T <sub>J</sub> = 125 °C		-	2.0	-	μC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	+175	°C
Thermal resistance, per diode junction to solder pad	R <sub>thJ-Sp</sub>		-	1.2	1.7	°C/W
Approximate weight				0.55		g
Approximate weight				0.02		oz.
Marking device		Case style TO-263AC (SMPD)		30CI	DU06	

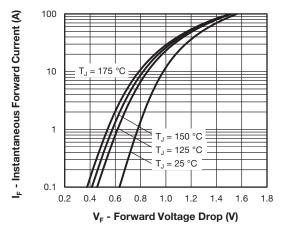


Fig. 1 - Typical Forward Voltage Drop Characteristics

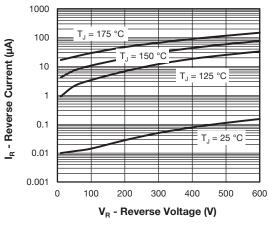


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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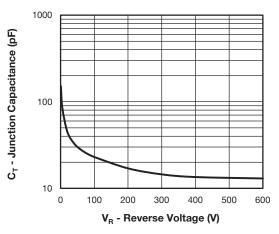


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

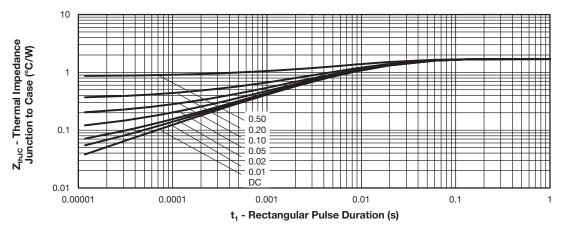


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

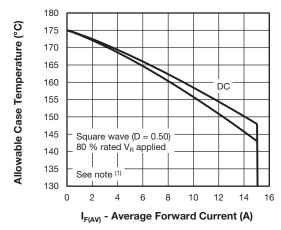


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

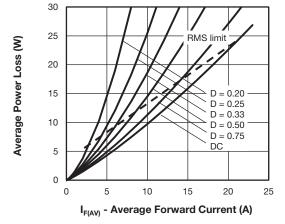


Fig. 6 - Forward Power Loss Characteristics

### Note

Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)}x$   $V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);  $Pd_{REV}$  = Inverse power loss =  $V_{R1}$  x  $I_{R}$  (1 - D);  $I_{R}$  at  $V_{R1}$  = rated  $V_{R}$ 

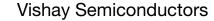
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## VS-30CDU06-M3



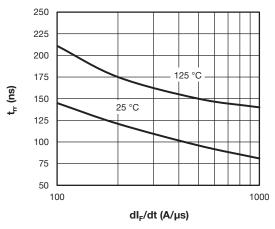


Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

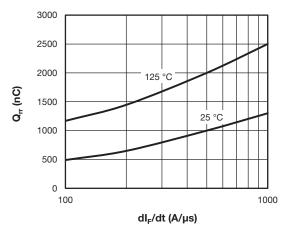
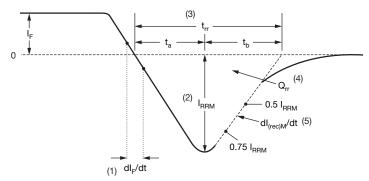


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>E</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (4) Q<sub>rr</sub> area under curve defined by t<sub>rr</sub> and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions

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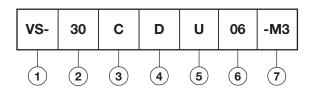


### VS-30CDU06-M3

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### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- Current rating (30 A)
- 3 Circuit configuration:
  - C = common cathode
- D = SMPD package
- 5 Process type,
  - U = ultrafast recovery
- 6 Voltage code (06 = 600 V)
- 7 -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-30CDU06-M3/I	2000	2000	13" diameter plastic tape and reel	

LINKS TO RELATED DOCUMENTS		
Dimensions www.vishay.com/doc?95604		
Part marking information	www.vishay.com/doc?95566	
Packaging information	www.vishay.com/doc?88869	



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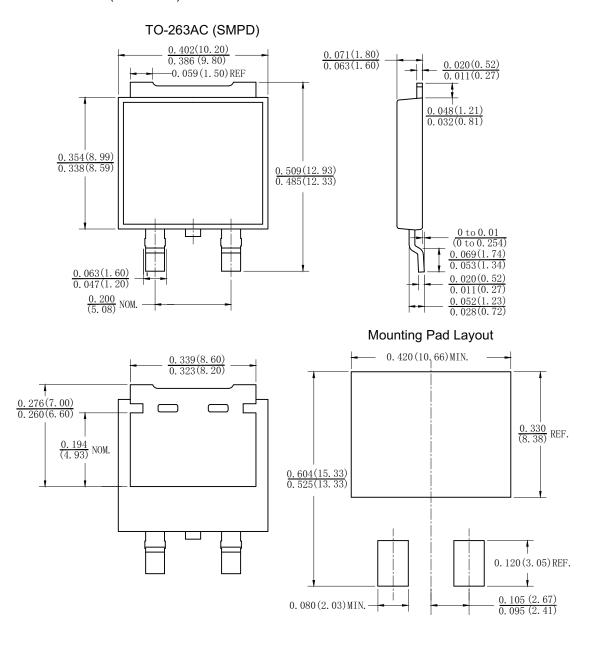


# **Outline Dimensions**

Vishay Semiconductors

# TO-263AC (SMPD)

### **DIMENSIONS** in inches (millimeters)





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Revision: 13-Jun-16 1 Document Number: 91000